NSN 5961-01-434-0312

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Inclosure Material:

Ceramic

Overall Length:

0.414 inches

Overall Height:

0.071 inches

Overall Width:

0.414 inches

End Application:

Pacer dawn

Mounting Method:

Terminal

Features Provided:

Electrostatic sensitive

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

25.0 collector to base voltage/static/emitter open and 12.0 collector to emitter voltage/static/base open and 3.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

70.00 milliamperes source cutoff current

Power Rating Per Characteristic:

290.0 milliwatts small-signal input power, common-emitter nanoamperes

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees fahrenheit junction

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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